

HAT2142H

Silicon N Channel Power MOS FET Power Switching

REJ03G1194-0800

Rev.8.00

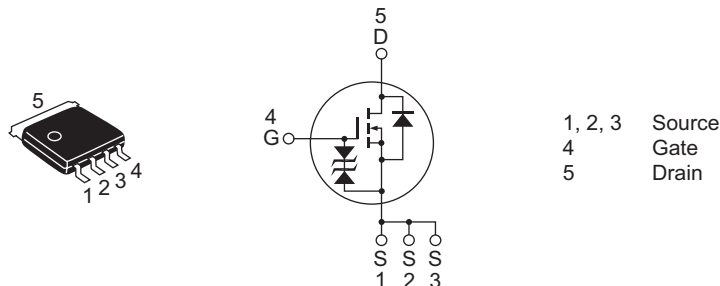
Jul 29, 2009

Features

- Capable of 7 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
 $R_{DS(on)} = 35 \text{ m}\Omega$ typ. (at $V_{GS} = 10 \text{ V}$)

Outline

RENESAS Package code: PTZZ0005DA-A
(Package name: LFPAK)



Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Drain to source voltage	V_{DSS}	100	V
Gate to source voltage	V_{GSS}	± 20	V
Drain current	I_D	10	A
Drain peak current	$I_{D(pulse)}$ ^{Note 1}	40	A
Body-drain diode reverse drain current	I_{DR}	10	A
Avalanche current	I_{AP} ^{Note 3}	10	A
Avalanche energy	E_{AR} ^{Note 3}	10	mJ
Channel dissipation	P_{ch} ^{Note 2}	15	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

- Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$
 2. $T_c = 25^\circ\text{C}$
 3. Value at $T_{ch} = 25^\circ\text{C}$, $R_g \geq 50 \Omega$

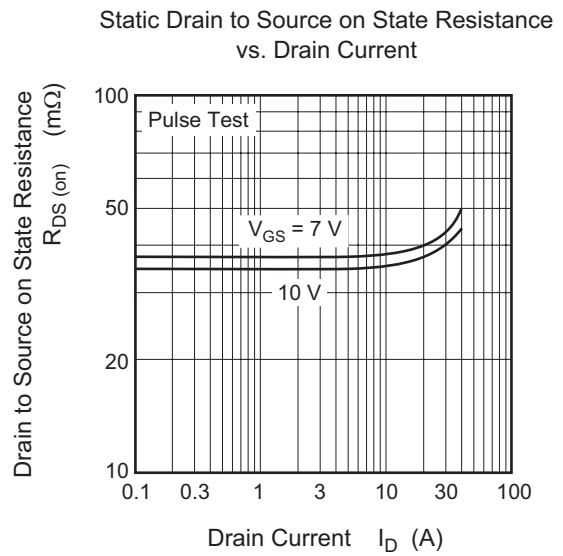
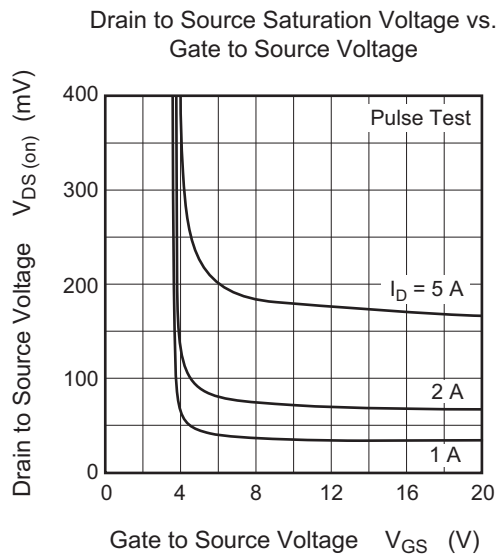
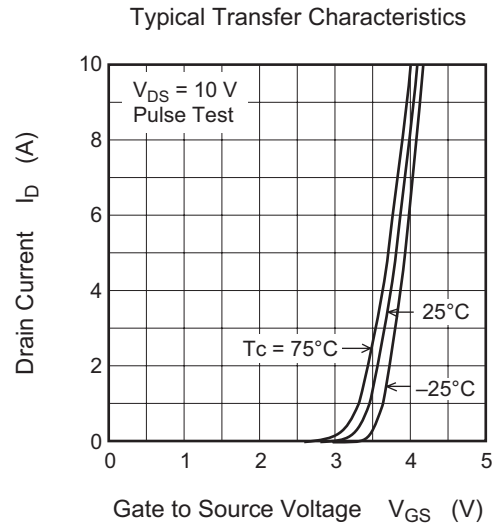
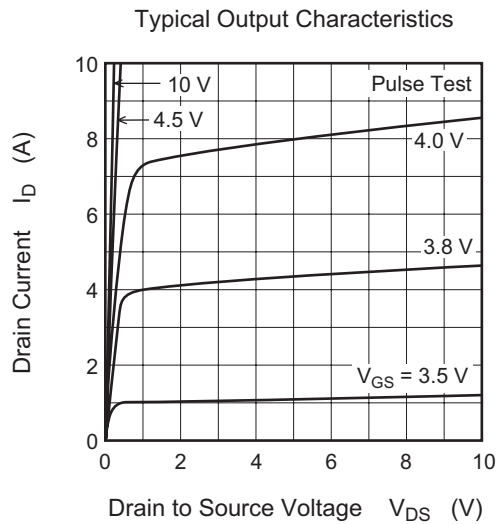
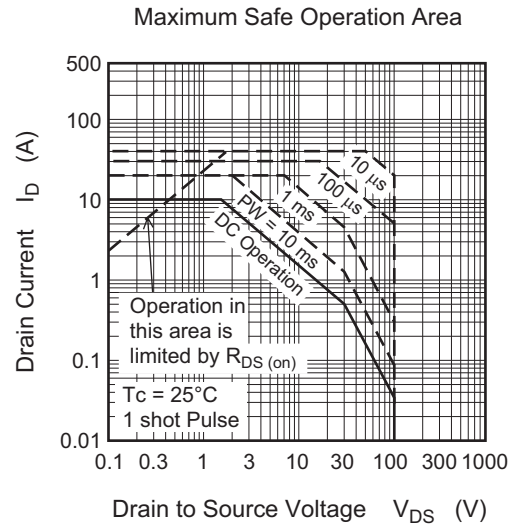
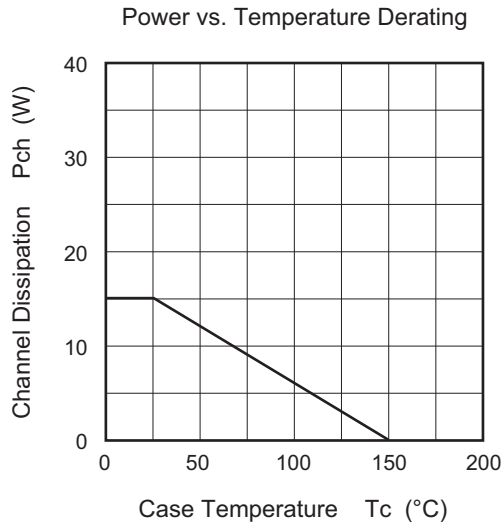
Electrical Characteristics

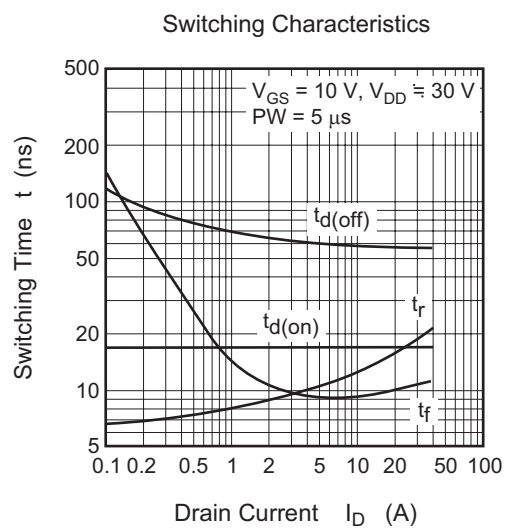
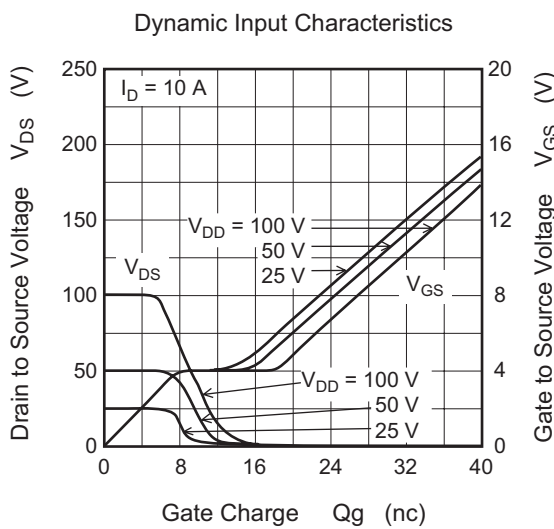
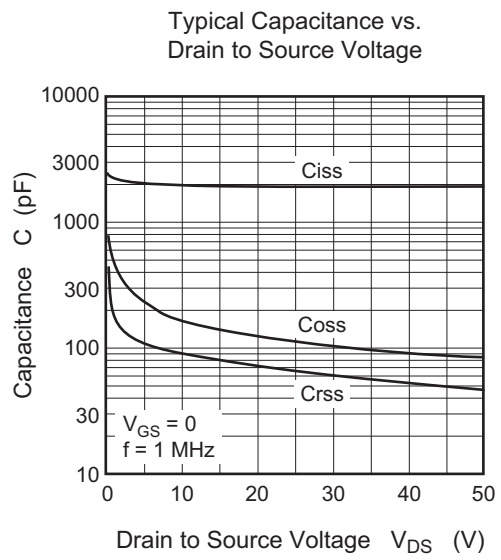
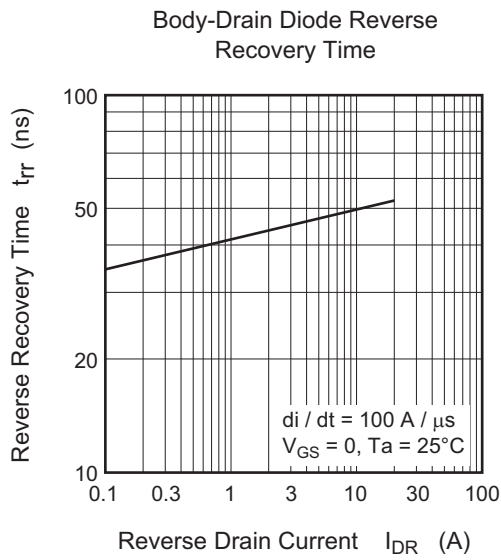
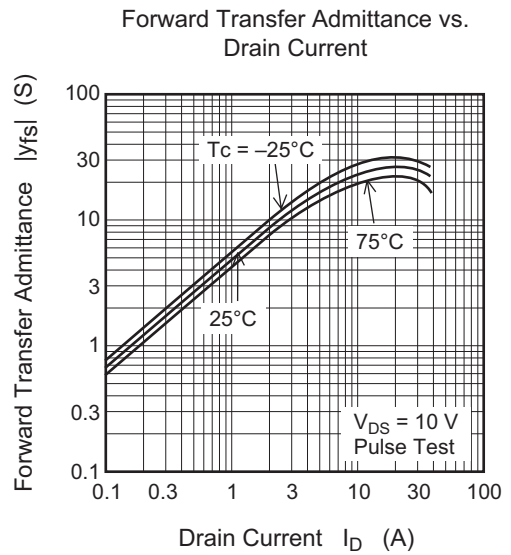
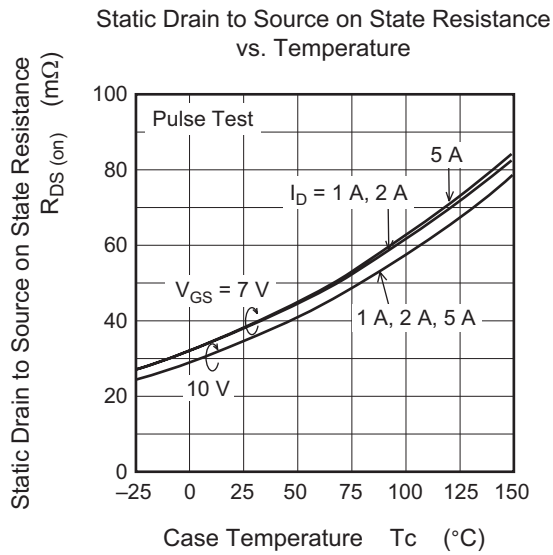
(Ta = 25°C)

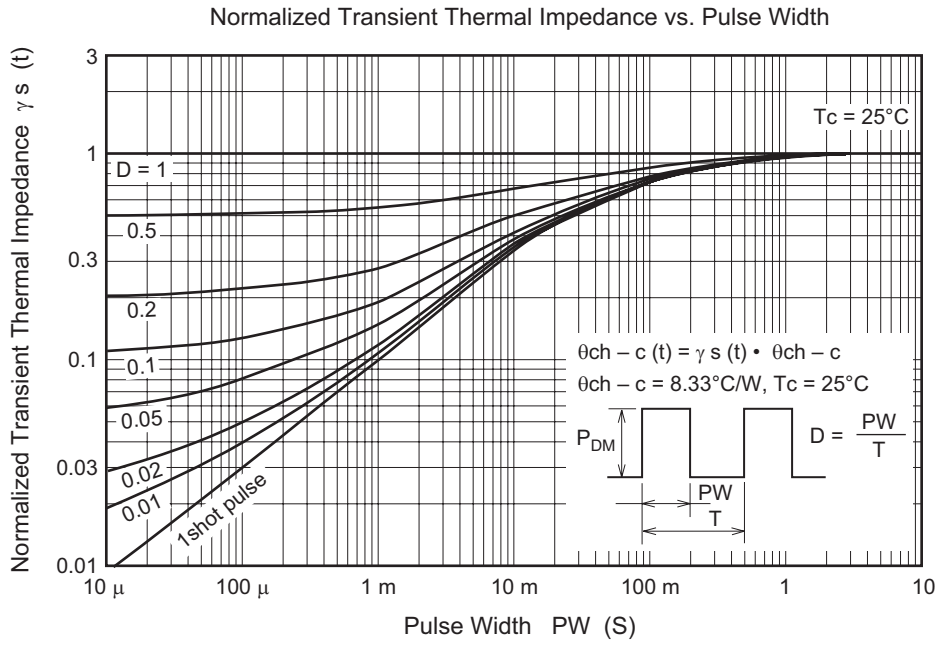
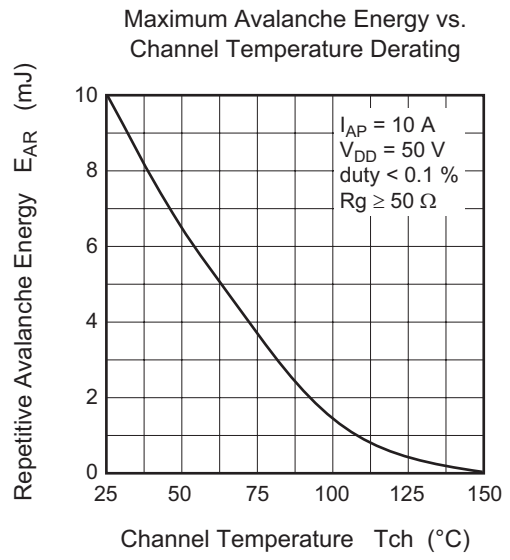
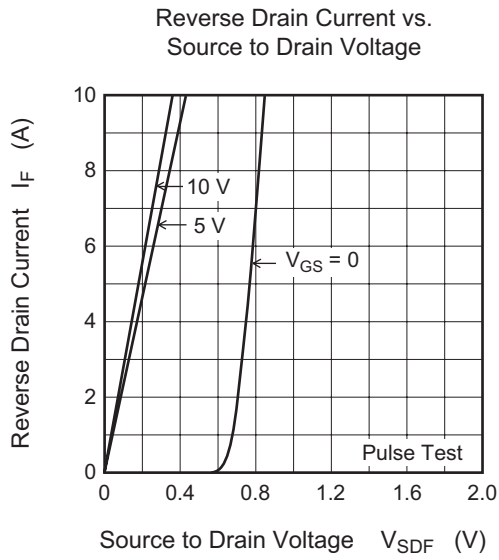
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 20	—	—	V	$I_G = \pm 100 \mu\text{A}$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 16 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 100 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.5	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	35	44	$\text{m}\Omega$	$I_D = 5 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note 4}
	$R_{DS(on)}$	—	38	51	$\text{m}\Omega$	$I_D = 5 \text{ A}$, $V_{GS} = 7 \text{ V}$ ^{Note 4}
Forward transfer admittance	$ y_{fs} $	9	15	—	S	$I_D = 5 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note 4}
Input capacitance	C_{iss}	—	2000	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	C_{oss}	—	175	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	90	—	pF	$f = 1 \text{ MHz}$
Total gate charge	Q_g	—	32	—	nC	$V_{DD} = 50 \text{ V}$
Gate to source charge	Q_{gs}	—	8.0	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	Q_{gd}	—	7.5	—	nC	$I_D = 10 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	18	—	ns	$V_{GS} = 10 \text{ V}$, $I_D = 5 \text{ A}$
Rise time	t_r	—	11	—	ns	$V_{DD} \cong 30 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	60	—	ns	$R_L = 6 \Omega$
Fall time	t_f	—	9	—	ns	$R_g = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	—	0.82	1.07	V	$I_F = 10 \text{ A}$, $V_{GS} = 0$ ^{Note 4}
Body-drain diode reverse recovery time	t_{rr}	—	50	—	ns	$I_F = 10 \text{ A}$, $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Note: 4. Pulse test

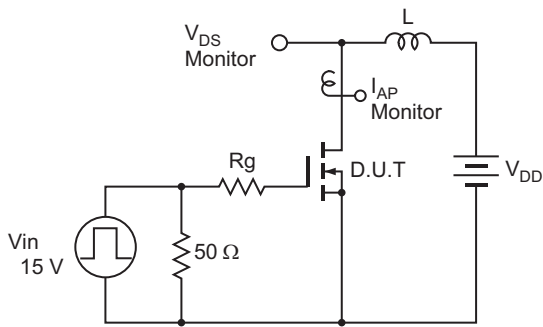
Main Characteristics



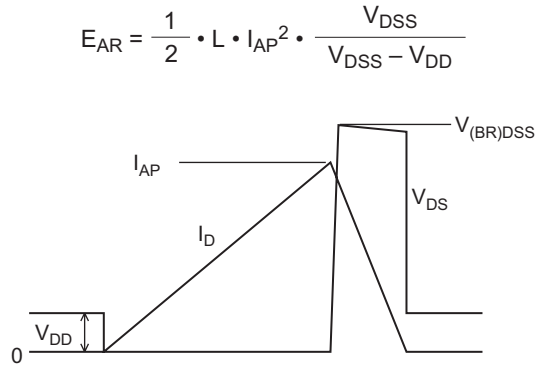


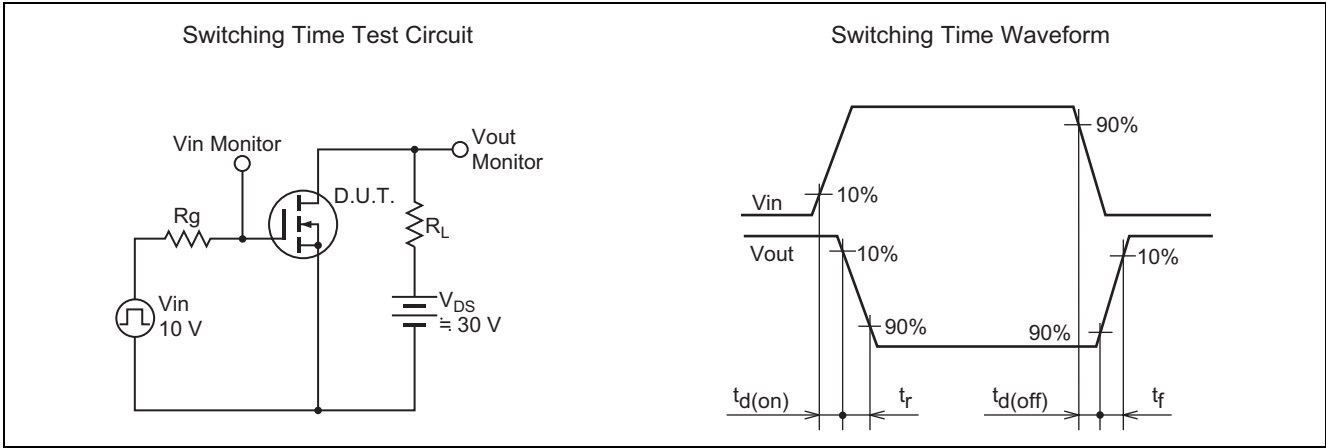


Avalanche Test Circuit

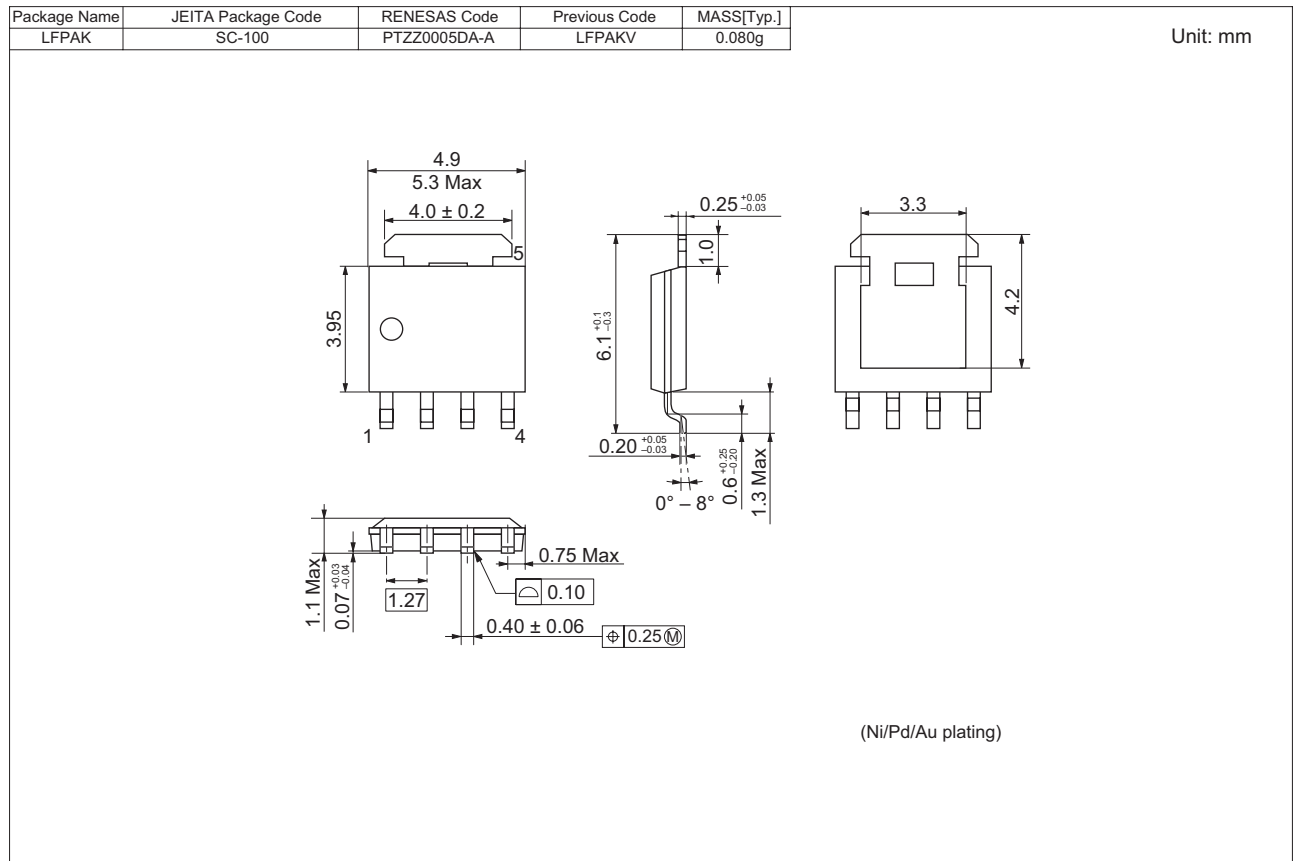


Avalanche Waveform





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
HAT2142H-EL-E	2500 pcs	Taping

Notes:

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